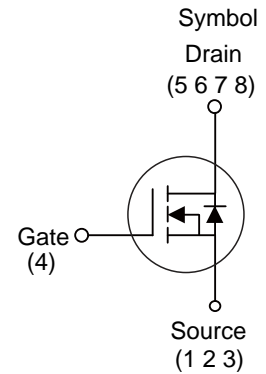


■ PRODUCT CHARACTERISTICS

V <sub>DSS</sub>	30V
R <sub>DS(ON)</sub> Typ(@V <sub>GS</sub> =10V)	9mΩ
R <sub>DS(ON)</sub> Typ(@V <sub>GS</sub> =4.5V)	13 mΩ
I <sub>D</sub>	35A

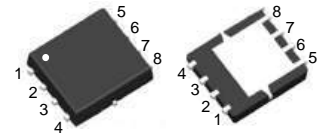


■ APPLICATIONS

- \* Electronic lamp ballasts based on half bridge
- \* Load Switching, Quick/Wireless Charge.
- \* Motor Driving

■ FEATURE

- \* Low Gate Charge
- \* Pb-Free Lead Plating



PDFN5X6

■ ORDER INFORMATION

Order Codes		Package	Packing
Halogen-Free	Halogen		
N/A	MOT3510G	PDFN5X6	5000 pieces/Reel

■ ABSOLUTE MAXIMUM RATINGS(T<sub>A</sub>=25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V <sub>DSS</sub>	30	V
Gate-Source Voltage	V <sub>GSS</sub>	± 20	V
Drain Current Continuous(@V <sub>GS</sub> =10V, T <sub>A</sub> =25°C)	I <sub>D</sub>	35	A
Drain Current Continuous(@V <sub>GS</sub> =10V, T <sub>A</sub> =100°C)	I <sub>D</sub>	24	A
Drain Current Pulsed	I <sub>DM</sub>	140	A
Avalanche Energy *	E <sub>AS</sub>	81	mJ
Power Dissipation	P <sub>D</sub>	25	W
Junction Temperature	T <sub>J</sub>	+150	°C
Storage Temperature	T <sub>STG</sub>	-55~ +150	°C

■ THERMAL CHARACTERISTICS

Parameter	Symbol	Typ	Unit
Junction to Case	R <sub>thJC</sub>	5	°C/W

Note: \* EAS condition: T<sub>J</sub>=25°C, V<sub>DD</sub>=24V, V<sub>G</sub>=10V, L=0.5mH, R<sub>g</sub>=25Ω

**■ ELECTRICAL CHARACTERISTICS** ( $T_C=25^{\circ}\text{C}$ , unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Off characteristics						
Drain to Source Breakdown Voltage	$V_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	30	-	-	V
Drain to Source Leakage Current	$I_{DSS}$	$V_{DS}=30V, V_{GS}=0V$	-	-	1	$\mu A$
Gate to Source Forward Leakage	$I_{GSS(F)}$	$V_{GS}=+20V, V_{DS}=0V$	-	-	100	nA
Gate to Source Reverse Leakage	$I_{GSS(R)}$	$V_{GS}=-20V, V_{DS}=0V$	-	-	-100	nA
On characteristics						
Drain to Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=10A$	-	9	11	m $\Omega$
		$V_{GS}=4.5V, I_D=10A$	-	13	16	m $\Omega$
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.45	2.5	V
Dynamic characteristics						
Gate capacitance	$R_g$	$V_{GS}=0V, V_{DS}=0V, f=1.0MHz$	-	3.4	-	$\Omega$
Forward Transconductance	$g_{fs}$	$V_{DS}=5V, I_D=5A$	-	9	-	S
Input Capacitance	$C_{iss}$	$V_{DS}=20V, V_{GS}=0V$ $f=1.0MHz$	-	706	-	pF
Output Capacitance	$C_{oss}$		-	129	-	pF
Reverse Transfer Capacitance	$C_{rss}$		-	77	-	pF
Resistive Switching Characteristics						
Turn-on Delay Time	$t_{d(ON)}$	$V_{GS}=10V, V_{DS}=15V,$ $I_D=10A, R_G=1.8\Omega$	-	10	-	ns
Rise Time	$t_r$		-	8	-	ns
Turn-off Delay Time	$t_{d(OFF)}$		-	30	-	ns
Fall Time	$t_f$		-	8	-	ns
Total Gate Charge	$Q_g$	$I_D=10A, V_{DS}=15V$ $V_{GS}=10V$	-	32	-	nC
Gate to Source Charge	$Q_{gs}$		-	4.9	-	nC
Gate to Drain("Miller") Charge	$Q_{gd}$		-	6.9	-	nC
Source-Drain Diode Characteristics						
Continuous Source Current(Body Diode)	$I_S$		-	-	35	A
Maximum Pulsed Current(Body Diode)	$I_{SM}$		-	-	140	A
Diode Forward Voltage	$V_{SD}$	$I_{SD}=1A, V_{GS}=0V$	-	0.74	1.2	V
Reverse Recovery Time	$t_{rr}$	$I_{SD}=10A, T_J=25^{\circ}\text{C}$ $di/dt=100A/\mu s$	-	32	-	ns
Reverse Recovery Charge	$Q_{rr}$		-	57	-	nC

■ TYPICAL CHARACTERISTICS

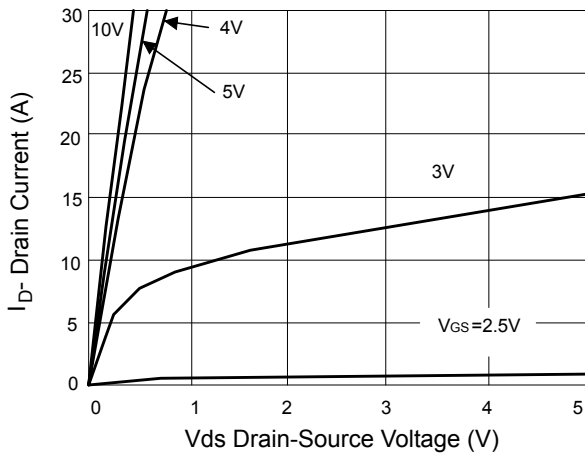


Figure 1 Output characteristics

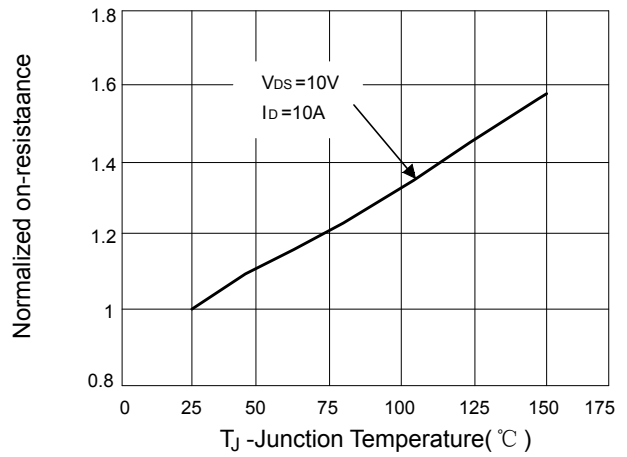


Figure 2  $R_{dson}$ -junction temperature

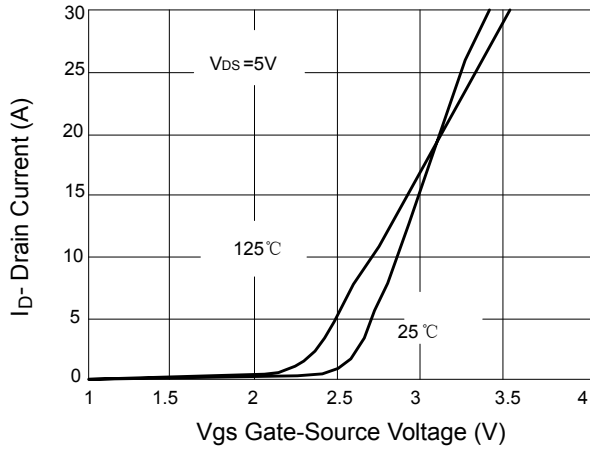


Figure 3 Transfer characteristics

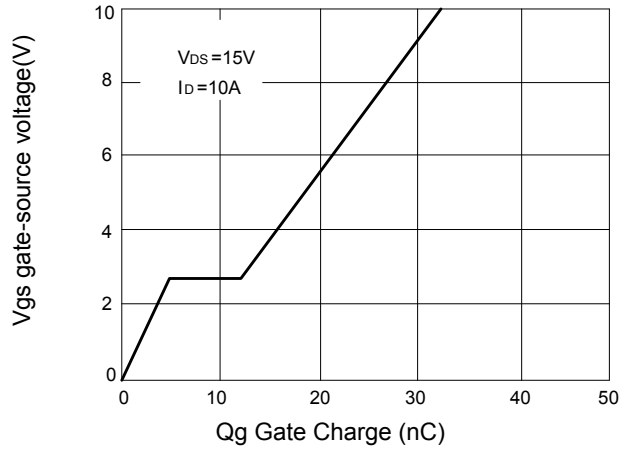


Figure 4 Gate charge characteristics

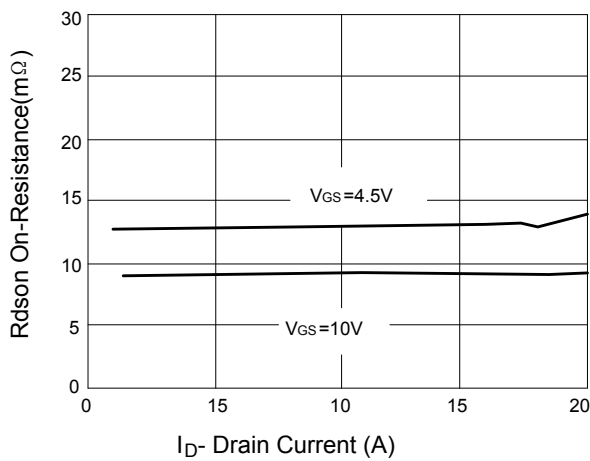


Figure 5  $R_{dson}$ -drain current

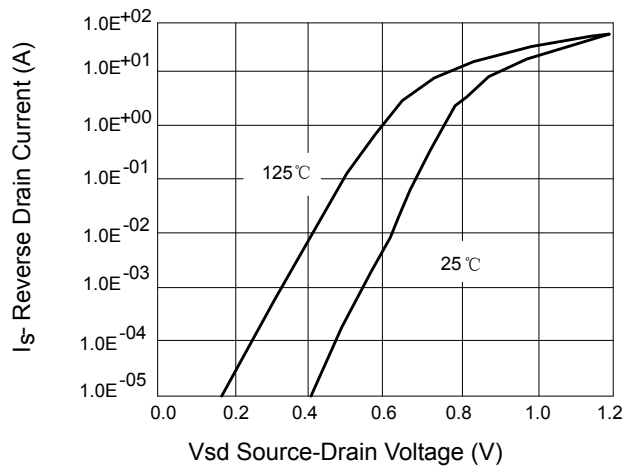


Figure 6 Source-drain diode forward

■ TYPICAL CHARACTERISTICS(Cont.)

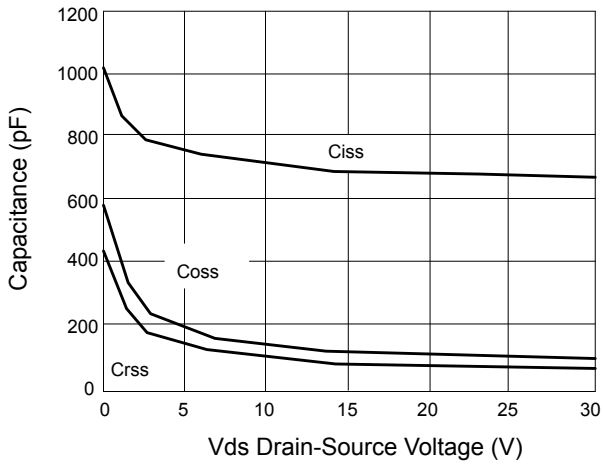


Figure 7 Capacitance vs. vds

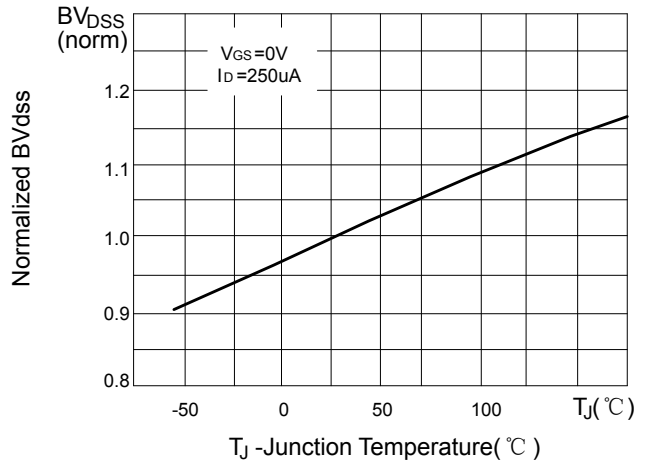


Figure 8  $BV_{DSS}$  vs. junction temperature

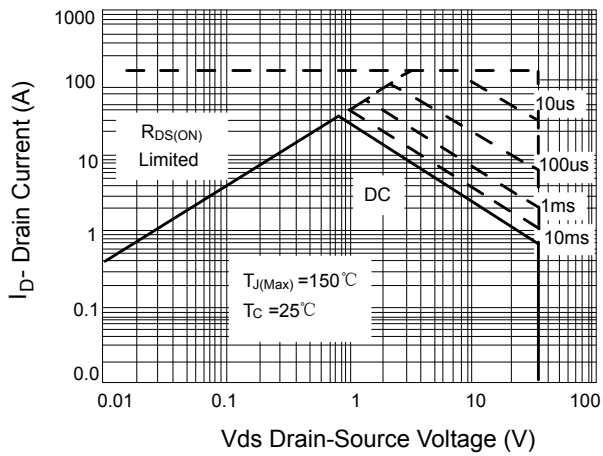


Figure 9 Safe operation area

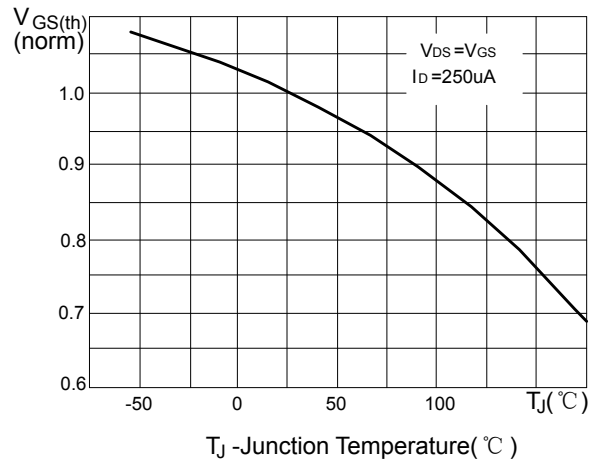
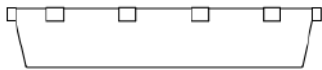
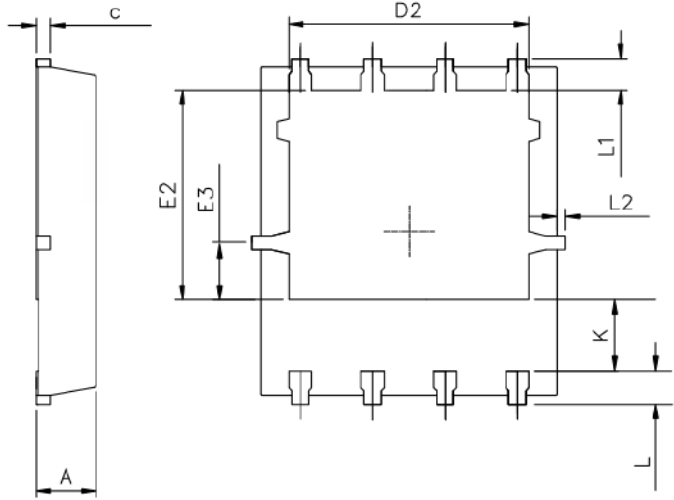
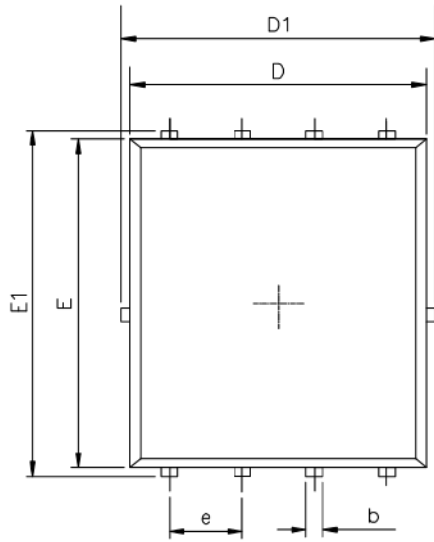
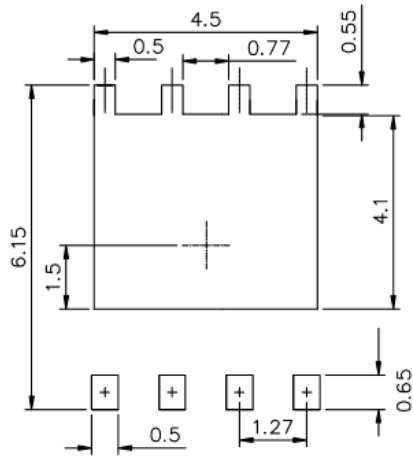


Figure 10  $V_{GS(th)}$  vs. junction temperature

■ PDFN5X6 PACKAGE OUTLINE DIMENSIONS



RECOMMENDED LAND PATTERN



UNIT:mm

	MIN	NOM	MAX
A	0.90	1.00	1.10
b	0.25	0.35	0.50
c	0.10	0.20	0.30
D	4.80	5.00	5.30
D1	4.90	5.10	5.50
D2	3.92	4.02	4.20
E	5.65	5.75	5.85
E1	5.90	6.05	6.20
E2	3.325	3.525	3.775
E3	0.80	0.90	1.00
e		1.27	
L	0.40	0.55	0.70
L1		0.65	
L2	0.00		0.15
K	1.00	1.30	1.50